

1.2A/1A, Hysteretic, High Brightness LED Driver with Internal Switch

General Description

The RT8471 is a high efficiency, continuous mode inductive step-down converter, designed for driving single or multiple series connected LEDs from a voltage source higher than the LED voltage. It operates from an input voltage of 7V to 36V and employs hysteretic control with a high side current sense resistor to set the constant output current.

The RT8471 includes an output switch and a high side output current sensing circuit, which uses an external resistor to set the nominal average output current. LED brightness control is achieved with PWM dimming from an analog or PWM input signal.

The RT8471 is available in a small TSOT-23-5 package or a more thermal efficient SOP-8 (Exposed Pad) and MSOP-8 (Exposed Pad) packages.

Ordering Information

RT8471

Package Type J5: TSOT-23-5

SP: SOP-8 (Exposed Pad-Option 1)

FP: MSOP-8 (Exposed Pad)

Lead Plating System

G: Green (Halogen Free and Pb Free) (for MSOP-8 (Exposed Pad) and TSOT-23-5)

Z : ECO (Ecological Element with Halogen Free and Pb free) (for SOP-8 (Exposed Pad) Only)

Note:

Richtek products are:

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

Features

- 7V to 36V Input Voltage Range
- Hysteretic Control with High Side Current Sensing
- Internal N-MOSFET with 350m Ω Low R_{DS(ON)}
- 1A Output Current (For TSOT-23-5 Only)
- 1.2A Output Current (For SOP-8 (Exposed Pad) and MSOP-8 (Exposed Pad) Only)
- Up to 97% Efficiency
- Typical ±5% LED Current Accuracy
- Analog or PWM Control Signal for LED Dimming
- 300Hz On-Board Ramp Generator
- Input Under Voltage Lockout
- Thermal Shutdown Protection
- RoHS Compliant and Halogen Free

Applications

- Automotive LED Lighting
- High Power LED Lighting
- Indicator and Emergency Lighting
- Architectural Lighting
- Low Voltage Industrial Lighting
- Signage and Decorative LED Lighting

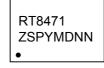
Marking Information

RT8471GJ5



01= : Product Code DNN : Date Code

RT8471ZSP



RT8471ZSP : Product Number

YMDNN: Date Code

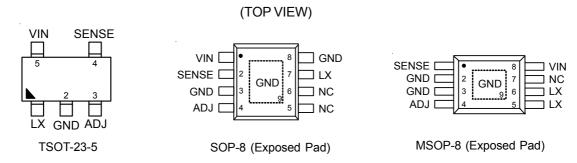
RT8471GFP



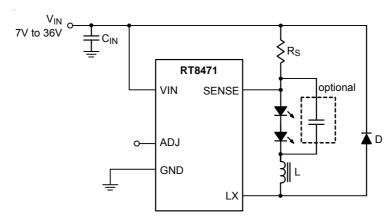
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Pin Configurations



Typical Application Circuit

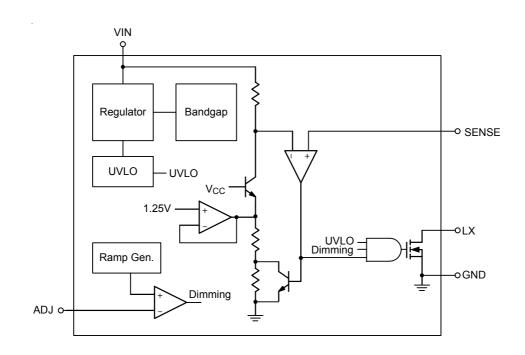


Functional Pin Description

		-			
	Pin No.				
TSOT-23-5	SOP-8 (Exposed Pad)	MSOP-8 (Exposed Pad)	Pin Name	Pin Function	
1	7	5, 6	LX	Switch Output Terminal. Drain of internal N-MOSFET.	
2	3, 8, 9 (Exposed Pad)	2, 3, 9 (Exposed Pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.	
3	4	4	ADJ	Dimming Control Input : Analog signal input for analog PWM dimming PWM signal input for digital PWM dimming.	
4	2	1	SENSE	Output Current Sense. Sense LED string current with an external resistor connected between VIN and SENSE.	
5	1	8	VIN	Supply Input Voltage.	
	5, 6	7	NC	No Internal Connection.	



Function Block Diagram





Absolute Maximum Ratings (Note 1)

 Supply Input Voltage, V_{IN}		0.0077
 Sense Voltage, SENSE (V_{IN} − 5V) to (V_{IN} + 0.3V) All Other Pins −0.3V to 6V Power Dissipation, P_D @ T_A = 25°C TSOT-23-5 (Two-layer PCB) 0.43W SOP-8 (Exposed pad, Two-layer PCB) 2.35W SOP-8 (Exposed pad, Four-layer PCB) 3.26W MSOP-8 (Exposed pad, Four-layer PCB) 1.38W MSOP-8 (Exposed pad, Four-layer PCB) 2.1W Package Thermal Resistance (Note 2) TSOT-23-5, θ_{JA} (Two-layer PCB) 21.8°C/W TSOT-23-5, θ_{JA} (Four-layer PCB) 21.8°C/W TSOT-23-5, θ_{JA} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ_{JA} 42.5°C/W SOP-8 (Exposed pad, Two-layer PCB), θ_{JA} MSOP-8 (Exposed pad, Four-layer PCB), θ_{JA} MSOP-8		
 All Other Pins		,
 Power Dissipation, P_D @ T_A = 25°C TSOT-23-5 (Two-layer PCB) TSOT-23-5 (Four-layer PCB) O.43W SOP-8 (Exposed pad, Two-layer PCB) SOP-8 (Exposed pad, Four-layer PCB) MSOP-8 (Exposed pad, Four-layer PCB) 1.38W MSOP-8 (Exposed pad, Four-layer PCB) 1.38W MSOP-8 (Exposed pad, Four-layer PCB) 2.1W Package Thermal Resistance (Note 2) TSOT-23-5, θ_{JA} (Two-layer PCB) TSOT-23-5, θ_{JA} (Two-layer PCB) 218°CW TSOT-23-5, θ_{JC} (Four-layer PCB) 230.6°CW TSOT-23-5, θ_{JC} (Four-layer PCB) 218°CW SOP-8 (Exposed pad, Two-layer PCB), θ_{JA} 42.5°CW SOP-8 (Exposed pad, Two-layer PCB), θ_{JA} SOP-8 (Exposed pad, Four-layer PCB), θ_{JA} SOP-8 (Exposed pad, Four-layer PCB), θ_{JA} SOP-8 (Exposed pad, Four-layer PCB), θ_{JA} MSOP-8 (Exposed pad, Two-layer PCB), θ_{JA} MSOP-8 (Exposed pad, Four-layer PCB), θ_{JA} Junction Temperature Junction Temperature Lead Temperature (Soldering, 10 sec.) Storage Temperature (Soldering, 10 sec.) Storage Temperature (Soldering, 10 sec.) ESD Susceptibility (Note 3) HBM (Human Body Model) MM (Machine Model) Supply Input Voltage, V_{IN} 7V to 36V 	•	, , , , , ,
TSOT-23-5 (Two-layer PCB)		–0.3V to 6V
TSOT-23-5 (Four-layer PCB)	, -	
SOP-8 (Exposed pad, Two-layer PCB) 2.35W SOP-8 (Exposed pad, Four-layer PCB) 3.26W MSOP-8 (Exposed pad, Two-layer PCB) 1.38W MSOP-8 (Exposed pad, Two-layer PCB) 2.1W • Package Thermal Resistance (Note 2) 264.4°CW TSOT-23-5, θ _{JA} (Two-layer PCB) 21.8°CW TSOT-23-5, θ _{JA} (Four-layer PCB) 230.6°CW TSOT-23-5, θ _{JA} (Four-layer PCB) 21.8°CW SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°CW SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 30.6°CW SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 30.6°CW SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°CW SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 72°CW MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°CW MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°CW MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°CW MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°CW	· · · · · · · · · · · · · · · · · · ·	
SOP-8 (Exposed pad, Four-layer PCB) 3.26W MSOP-8 (Exposed pad, Two-layer PCB) 1.38W MSOP-8 (Exposed pad, Four-layer PCB) 2.1W • Package Thermal Resistance (Note 2) 250.00 TSOT-23-5, θ _{JA} (Two-layer PCB) 264.4°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 21.8°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 230.6°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 34°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W<		
MSOP-8 (Exposed pad, Two-layer PCB) 1.38W MSOP-8 (Exposed pad, Four-layer PCB) 2.1W • Package Thermal Resistance (Note 2) 264.4°C/W TSOT-23-5, θ _{JA} (Two-layer PCB) 264.4°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 21.8°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 230.6°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 11.9°C/W Junction Temperature 150°C • Lead Temperature (Soldering, 10 sec.) 260°C • Storage Temperature (Soldering, 10 sec.) 260°C • ESD Susceptibility (Note 3) 14.8°C/W <td< td=""><td></td><td></td></td<>		
MSOP-8 (Exposed pad, Four-layer PCB)	SOP-8 (Exposed pad, Four-layer PCB)	3.26W
 Package Thermal Resistance (Note 2) TSOT-23-5, θ_{JA} (Two-layer PCB)	MSOP-8 (Exposed pad, Two-layer PCB)	1.38W
TSOT-23-5, θ _{JA} (Two-layer PCB) 264.4°C/W TSOT-23-5, θ _{JC} (Two-layer PCB) 21.8°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 230.6°C/W TSOT-23-5, θ _{JC} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 3.4°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 260°C • Lead Temperature (Soldering, 10 sec.) 260°C • Storage Temperature Range -65°C to 150°C • ESD Susceptibility (Note 3) 200V Recommended Operating Conditions (Note 4)	MSOP-8 (Exposed pad, Four-layer PCB)	2.1W
TSOT-23-5, θ _{JC} (Two-layer PCB) 21.8°C/W TSOT-23-5, θ _{JA} (Four-layer PCB) 230.6°C/W TSOT-23-5, θ _{JC} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 11.9°C/W Junction Temperature 150°C Lead Temperature (Soldering, 10 sec.) 260°C Storage Temperature Range -65°C to 150°C ESD Susceptibility (Note 3) 18M (Human Body Model) 2kV MM (Machine Model) 200V Recommended Operating Conditions (Note 4) Supply Input Voltage, V _{IN} 7V to 36V	Package Thermal Resistance (Note 2)	
TSOT-23-5, θ _{JA} (Four-layer PCB) 230.6°C/W TSOT-23-5, θ _{JC} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 34°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 11.9°C/W Junction Temperature 150°C Lead Temperature (Soldering, 10 sec.) 260°C • Storage Temperature Range -65°C to 150°C • ESD Susceptibility (Note 3) 2kV MM (Machine Model) 2kV MM (Machine Model) 200V	TSOT-23-5, θ _{JA} (Two-layer PCB)	264.4°C/W
TSOT-23-5, θ _{JC} (Four-layer PCB) 21.8°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 42.5°C/W SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 3.4°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 3.4°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 11.9°C/W Junction Temperature 150°C Lead Temperature (Soldering, 10 sec.) 260°C Storage Temperature Range -65°C to 150°C ESD Susceptibility (Note 3) 2kV MM (Machine Model) 2kV MM (Machine Model) 200V Recommended Operating Conditions (Note 4) Supply Input Voltage, V _{IN} 7V to 36V	TSOT-23-5, θ _{JC} (Two-layer PCB)	21.8°C/W
$SOP-8 \ (Exposed pad, Two-layer PCB), \theta_{JA}$	TSOT-23-5, θ _{JA} (Four-layer PCB)	230.6°C/W
SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 3.4°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 3.4°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JC} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 11.9°C/W • Junction Temperature 150°C • Lead Temperature (Soldering, 10 sec.) 260°C • Storage Temperature Range -65°C to 150°C • ESD Susceptibility (Note 3) 2kV MBM (Human Body Model) 2kV MM (Machine Model) 200V Recommended Operating Conditions (Note 4) • Supply Input Voltage, V _{IN} 7V to 36V	TSOT-23-5, θ _{JC} (Four-layer PCB)	21.8°C/W
SOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 3.4°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 30.6°C/W SOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 3.4°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JA} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JC} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 11.9°C/W • Junction Temperature 150°C • Lead Temperature (Soldering, 10 sec.) 260°C • Storage Temperature Range -65°C to 150°C • ESD Susceptibility (Note 3) 2kV MBM (Human Body Model) 2kV MM (Machine Model) 200V Recommended Operating Conditions (Note 4) • Supply Input Voltage, V _{IN} 7V to 36V	SOP-8 (Exposed pad, Two-layer PCB), θ _{JA}	42.5°C/W
$SOP-8 \ (Exposed pad, Four-layer PCB), \theta_{JA}$		
$SOP-8 \ (Exposed pad, Four-layer PCB), \theta_{JA}$	SOP-8 (Exposed pad, Four-layer PCB), θ _{JA}	30.6°C/W
MSOP-8 (Exposed pad, Two-layer PCB), θ _{JC} 72°C/W MSOP-8 (Exposed pad, Two-layer PCB), θ _{JC} 11.9°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JA} 47.4°C/W MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 11.9°C/W • Junction Temperature 150°C • Lead Temperature (Soldering, 10 sec.) 260°C • Storage Temperature Range -65°C to 150°C • ESD Susceptibility (Note 3) 2kV MM (Machine Model) 2kV MM (Machine Model) 200V Recommended Operating Conditions (Note 4) • Supply Input Voltage, V _{IN} 7V to 36V		
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$ MSOP-8 \ (Exposed pad, Four-layer PCB), \theta_{JA}$		
MSOP-8 (Exposed pad, Four-layer PCB), θ _{JC} 11.9°C/W Junction Temperature 150°C Lead Temperature (Soldering, 10 sec.) 260°C Storage Temperature Range -65°C to 150°C ESD Susceptibility (Note 3) 2kV MM (Machine Model) 200V Recommended Operating Conditions (Note 4) • Supply Input Voltage, V _{IN} 7V to 36V		
 Junction Temperature — 150°C Lead Temperature (Soldering, 10 sec.) — 260°C Storage Temperature Range — 65°C to 150°C ESD Susceptibility (Note 3) HBM (Human Body Model) — 2kV MM (Machine Model) — 200V Recommended Operating Conditions (Note 4) Supply Input Voltage, V_{IN} — 7V to 36V 		
 Lead Temperature (Soldering, 10 sec.)		
 Storage Temperature Range		
• ESD Susceptibility (Note 3) HBM (Human Body Model)		
HBM (Human Body Model)		
MM (Machine Model)	· · · · · · · · · · · · · · · · · · ·	2kV
Recommended Operating Conditions (Note 4) • Supply Input Voltage, V _{IN}		
• Supply Input Voltage, V _{IN} 7V to 36V	(200.
11.5	Recommended Operating Conditions (Note 4)	
• Junction Temperature Range	Supply Input Voltage, V _{IN}	7V to 36V
	Junction Temperature Range	



Electrical Characteristics

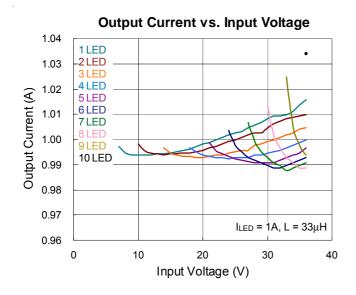
 $(V_{IN} = 12V, T_A = 25^{\circ}C, unless otherwise specified)$

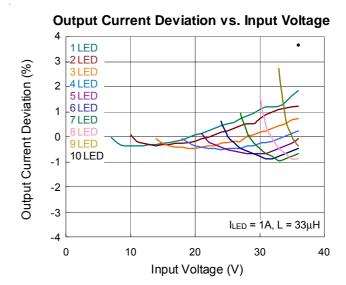
Paramet	er	Symbol	Test Conditions	Min	Тур	Max	Unit	
Mean Current Sense Threshold Voltage		V _{SENSE}	Measure on SENSE Pin with Respecting to V _{IN} . ADJ is Floating.	95	100	105	mV	
Sense Threshold Hy	steresis	ΔV_{SENSE}			±15	-	%	
Low Side Switch On-	-Resistance	R _{DS(ON)}			350	500	mΩ	
Low Side Switch Lea	kage Current		V_{LX} = 12V, V_{ADJ} = 0V		0.01	10	μΑ	
Under Voltage Locko	out Threshold	V_{UVLO}	VIN Rising		5.2		V	
Under Voltage Locko Hysteresis	Under Voltage Lockout Threshold Hysteresis				400	ı	mV	
Ramp Frequency		f _{RAMP}			300		Hz	
ADJ Input Threshold	Logic-High	$V_{ADJ,H}$		1.4			- V	
Voltage	Logic-Low	V _{ADJ, L}		_		0.2		
Analog Dimming Rai	nge			0.3		1.3	V	
Analog Dimming	Logic-High				1.2	1.3	V	
Threshold Voltage	Logic-Low			0.3	0.4			
Minimum Switch On-	Time	ton(MIN)	LX Switch On		210		ns	
Minimum Switch Off-	-Time	t _{OFF(MIN)}	LX Switch Off	_	170		ns	
Quiescent Input Current with Output Off		I _{VIN, Off}	V _{ADJ} = 0V		450		μА	
Quiescent Input Current with Output Switching		I _{VIN} , On	ADJ is Floating, fsw = 250kHz, V _{IN} = 8V	_	1000		μА	
Internal Propagation Delay		t _{PD}			25	-	ns	
Sense Pin Input Current		I _{SENSE}	$V_{SENSE} = V_{IN} - 0.1V$	_	300	-	nA	
Thermal Shutdown		T _{SD}			150	1	°C	
Thermal Shutdown Hysteresis		ΔT_{SD}			30		°C	

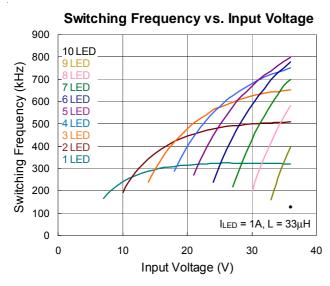
- **Note 1.** Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.
- Note 2. θ_{JA} is measured in natural convection at T_A = 25°C on a two-layer and four-layer test board of JEDEC 51 thermal measurement standard. For SOP-8 (Exposed Pad) and MSOP-8 (Exposed Pad) the measurement case position of θ_{JC} is on the exposed pad of the package. For TSOT-23-5, the measurement case position of θ_{JC} is on the lead of the package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

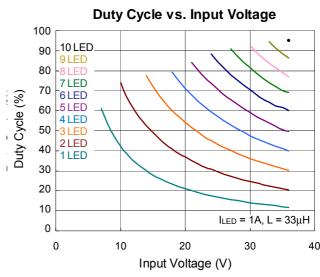


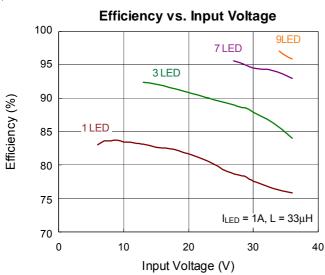
Typical Operating Characteristics

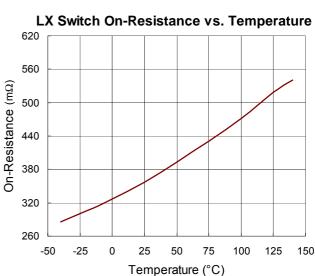




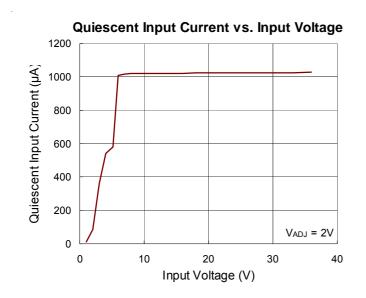


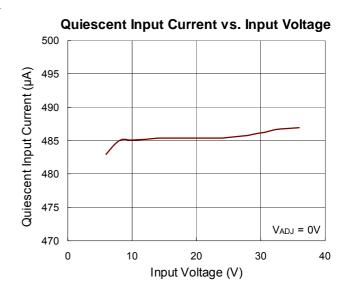


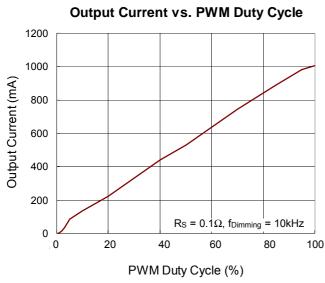


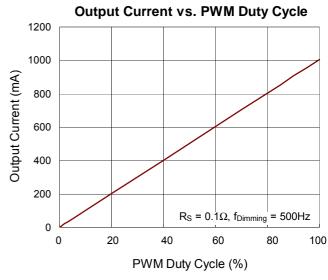


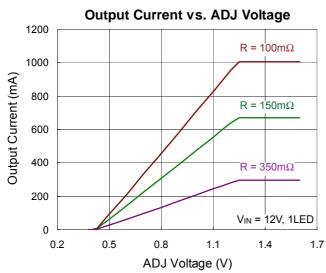


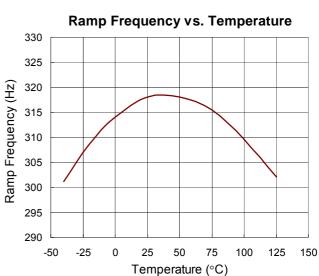








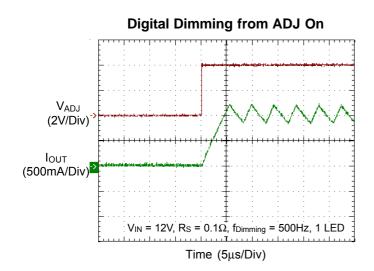


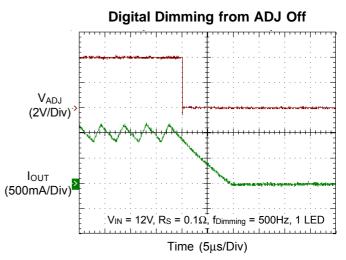


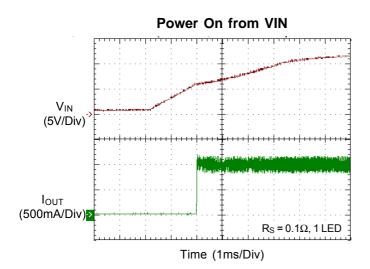
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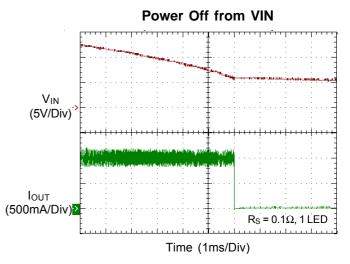
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Application Information

The RT8471 is a simple high efficiency, continuous mode inductive step-down converter. The device operates with an input voltage range from 7V to 36V and delivers up to 1.2A of output current. A high side current sense resistor sets the output current. A dedicated PWM dimming input enables pulsed LED dimming over a wide range of brightness levels. A high side current sensing scheme and an onboard current setting circuitry minimize the number of external components. A 1% sense resistor performs a $\pm 5\%$ LED current accuracy for the best performance.

Under Voltage Lockout (UVLO)

The RT8471 includes a UVLO feature with 400mV hysteresis. The internal MOSFET turns off when V_{IN} falls below 4.8V (typ.).

Setting Average Output Current

The RT8471 output current which flows through the LEDs is set by an external resistor (Rs) connected between the VIN and SENSE terminal. The relationship between output current (I_{OUT}) and Rs is shown as below :

$$I_{OUTavg} = \frac{0.1V}{R_S}$$
 (A)

Analog Dimming Control

The ADJ terminal can be driven by an external voltage (V_{ADJ}) to adjust the average output current. The average output current is given by :

$$I_{OUTavg} = \left(\frac{0.1V}{R_S}\right) \times \frac{V_{ADJ} - 0.4}{0.8}$$

where V_{ADJ} is ranged from 0.4V to 1.2V. When V_{ADJ} is larger than 1.2V, the output current value will only depend on the external resistor (R_S).

Digital Dimming Control

A Pulse Width Modulated (PWM) signal can drive the ADJ terminal directly. Notice that the PWM signal logic high level must be above 1.4V and the logic low level must be below 0.2V at the ADJ terminal. It's recommended to maintain the PWM dimming at low frequency (ex. 500Hz) in order to obtain a linear dimming curve.

PWM Soft-Start Behavior

The RT8471 features an optional PWM soft-start behavior that allows for gradual brightness transition. This is achieved by simply connecting an external capacitor between the ADJ pin and GND. An internal current source will then charge this capacitor for soft-start behavior, resulting in steady LED current increase and decrease during power on and power off, as shown in Figure 1.

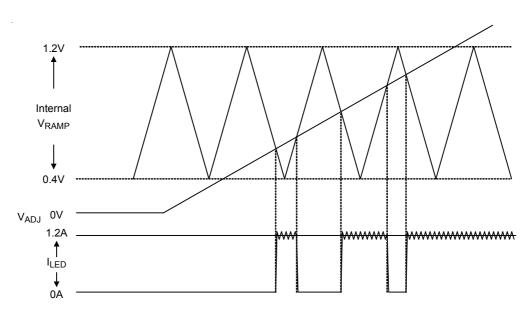


Figure 1. PWM Soft-Start Behavior Mechanism



The capacitor can be selected according to below equation:

$$C = 1.5 \times 10^{-6} \times t_{SS}$$

where t_{ss} is the soft-start period.

LED Current Ripple Reduction

Higher LED current ripple will shorten the LED life time and increase heat accumulation of LED. There are two ways to reduce the LED current ripple. One way is by increasing the inductance to lower LED current ripple in absence of an output capacitor. The other way is by adding an output capacitor in parallel with the LED. This will then allow the use of a smaller inductor.

Inductor Selection

The inductance is determined by inductor current ripple, switching frequency, duty ratio, circuit specifications and component parameters, as expressed in the following equation:

$$L > \left[V_{\text{IN}} - V_{\text{OUT}} - V_{\text{SEN}} - \left(R_{\text{DS(ON)}} \times I_{\text{OUT}}\right)\right] \times \frac{D}{f_{\text{SW}} \times \Delta I_{l}}$$

where

f_{SW} is the switching frequency (Hz)

R_{DS(ON)} is the low side switch on-resistance of internal MOSFET (= 0.35Ω typical)

D is the duty cycle determined by V_{OUT}/V_{IN}

IOUT is the required LED current (A)

∆l_L is the inductor peak-peak ripple current (internally set to 0.3 x I_{OUT})

V_{IN} is the input supply voltage (V)

V_{OUT} is the total LED forward voltage (V)

Besides, the selected inductance has also to satisfy the limit of the minimum switch on/off time. The calculated on time must be greater than 210ns of the minimum on time, and the off time must be greater than 170ns of the minimum off time. The following equation can be used to verify the suitability of the inductor value.

$$t_{ON} = \frac{L \times \Delta I_L}{V_{IN} - V_{OUT} - I_{OUT} \left(R_{SEN} + R_L + R_{DS(ON)}\right)}$$

$$> t_{ON(MIN)}(210 \text{ns typ.})$$

$$\begin{split} t_{OFF} = & \frac{L \times \Delta I_L}{V_{OUT} + V_D + V_{SEN} + \left(I_{OUT} \times R_L\right)} \\ > & t_{OFF(MIN)}(170 ns \ typ.) \end{split}$$

where

V_D is the rectifier diode forward voltage (V)

V_{SEN} is the voltage cross current sense resistor (V)

 R_L is the inductor DC resistance (Ω)

L is the inductance (H)

The saturation current of the selected inductor must be higher than the peak output LED current, and the continuous current rating must be above the average output LED current. In general, the inductor saturation current should be 1.5 times the LED current. In order to reduce the output current ripple, a higher inductance is recommended at higher supply voltages. However, it could also cause a higher line resistance and result in a lower efficiency.

Diode selection

To obtain better efficiency, the Schottky diode is recommended for its low reverse leakage current, low recovery time and low forward voltage. With its low power dissipation, the Schottky diode outperforms other silicon diodes and increase overall efficiency.

Input Capacitor selection

Input capacitor has to supply peak current to the inductor and flatten the current ripple on the input. The low ESR condition is required to avoid increasing power loss. The ceramic capacitor is recommended due to its excellent high frequency characteristic and low ESR, which are suitable for the RT8471. For maximum stability over the entire operating temperature range, capacitors with better dielectric are suggested.

Thermal Protection

A thermal protection feature is included to protect the RT8471 from excessive heat damage. When the junction temperature exceeds a threshold of 150°C, the thermal protection will turn off the LX terminal. When the junction temperature drops below 120°C, the RT8471 will turn back on the LX terminal and return to normal operations.

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Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For TSOT-23-5 packages, the thermal resistance, θ_{JA} , is 264.4°C/W on a standard JEDEC 51-3 two-layer thermal test board and 230.6°C/W on a standard JEDEC 51-7 fourlayer thermal test board. For SOP-8 (Exposed pad) package, the thermal resistance, θ_{JA} , is 42.5°C/W on a standard JEDEC 51-7 two-layer thermal test board, and 30.6°C/W on a standard JEDEC 51-7 four-layer thermal test board. For MSOP-8 (Exposed pad) package, the thermal resistance, θ_{JA} , is 72°C/W on a standard JEDEC 51-7 two-layer thermal test board, and 47.4°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at T_A= 25°C can be calculated by the following formulas:

 $P_{D(MAX)}$ = (125°C - 25°C) / (264.4°C/W) = 0.37W for TSOT-23-5 package (Two-Layer PCB)

 $P_{D(MAX)}$ = (125°C - 25°C) / (230.6°C/W) = 0.43W for TSOT-23-5 package (Four-Layer PCB)

 $P_{D(MAX)}$ = (125°C - 25°C) / (42.5°C/W) = 2.35W for SOP-8 (Exposed pad, Two-Layer PCB) package

 $P_{D(MAX)}$ = (125°C - 25°C) / (30.6°C/W) = 3.26W for SOP-8 (Exposed pad, Four-Layer PCB) package

 $P_{D(MAX)}$ = (125°C - 25°C) / (72°C/W) = 1.38W for MSOP-8 (Exposed pad, Two-Layer PCB) package

 $P_{D(MAX)}$ = (125°C - 25°C) / (47.4°C/W) = 2.1W for MSOP-8 (Exposed pad, Four-Layer PCB) package

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . The derating curves in Figure 2 allow the designer to see the effect of rising ambient temperature on the maximum power dissipation.

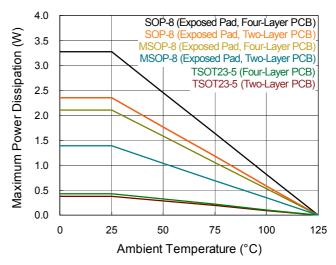


Figure 2. Derating Curves of Maximum Power Dissipation



Layout Considerations

For best performance of the RT8471, please abide the following layout guide.

- The capacitor C_{IN}, C_{ADJ} and external resistor, R_S, must be placed as close as possible to the VIN and SENSE pins of the device respectively.
- The GND should be connected to a strong ground plane.
- ▶ Keep the main current traces as short and wide as possible.
- ▶ The inductor (L) should be mounted as close to the device with low resistance connections.
- ► The ADJ pin trace need to be kept far away from LX terminal.

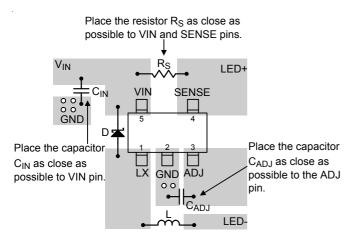
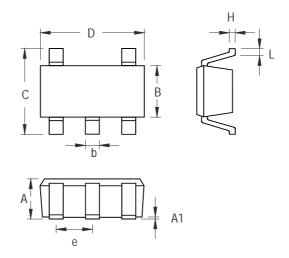


Figure 3. PCB Layout Guide



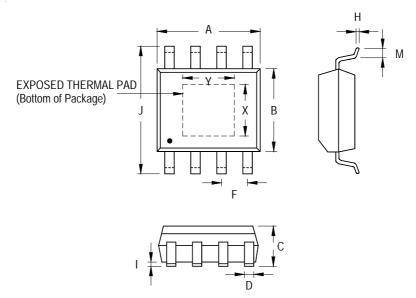
Outline Dimension



0	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min Max		Min	Max	
Α	0.700	1.000	0.028	0.039	
A1	0.000	0.100	0.000	0.004	
В	1.397	1.803	0.055	0.071	
b	0.300	0.559	0.012	0.022	
С	2.591	3.000	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.838	1.041	0.033	0.041	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

TSOT-23-5 Surface Mount Package

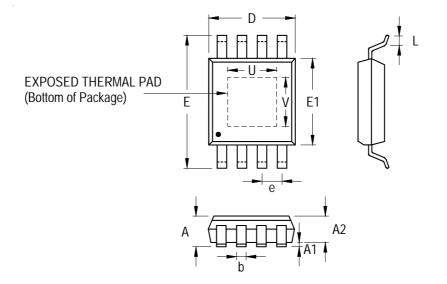




Symbol		Dimensions	In Millimeters	Dimensions In Inches		
		Min	Max	Min	Max	
А		4.801	5.004	0.189	0.197	
В		3.810	4.000	0.150	0.157	
С		1.346	1.753	0.053	0.069	
D		0.330	0.510	0.013	0.020	
F		1.194	1.346	0.047	0.053	
Н		0.170	0.254	0.007	0.010	
I		0.000	0.152	0.000	0.006	
J		5.791	6.200	0.228	0.244	
М		0.406	1.270	0.016	0.050	
Option 1	Х	2.000	2.300	0.079	0.091	
	Υ	2.000	2.300	0.079	0.091	
Option 2	Х	2.100	2.500	0.083	0.098	
	Υ	3.000	3.500	0.118	0.138	

8-Lead SOP (Exposed Pad) Plastic Package





0	Dimensions I	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	0.810	1.100	0.032	0.043	
A1	0.000	0.150	0.000	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.220	0.380	0.009	0.015	
D	2.900	3.100	0.114	0.122	
е	0.650		0.026		
Е	4.800	5.000	0.189	0.197	
E1	2.900	3.100	0.114	0.122	
L	0.400	0.800	0.016	0.031	
U	1.300	1.700	0.051	0.067	
V	1.500	1.900	0.059	0.075	

8-Lead MSOP (Exposed Pad) Plastic Package

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